

Ultra Low Noise pHEMT Dual Channel Amplifier, 1.710-1.910 GHz

**AM40-0023
V3**

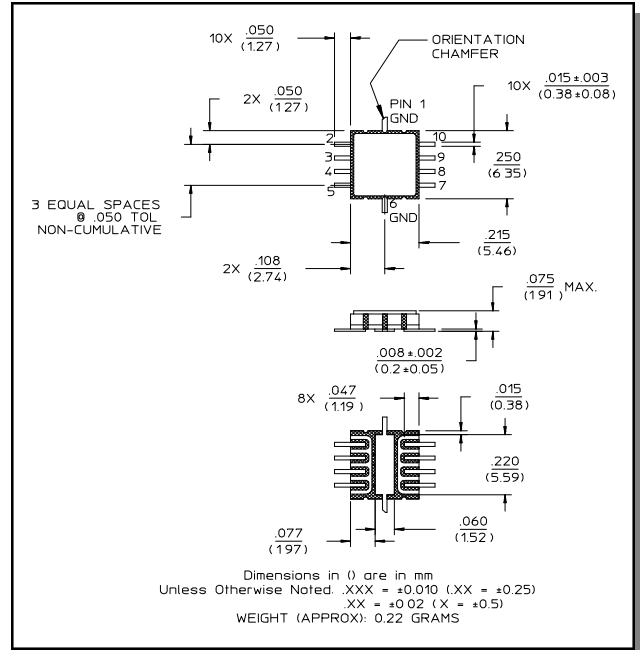
Features

- 0.7 dB Typical Noise Figure
- 14 dB Typical Gain
- DC Decoupled RF Input and Output
- Single Bias Configuration
- SMT Construction
- Dual Channels for Balanced Designs
- Unconditionally Stable—No External Matching Circuit required

Description

M/A-COM's AM40-0023 is a dual-channel, ultra low noise amplifier in a surface mount package. Very low noise figure is achieved by using discrete pHEMT devices combined with M/A-COM's glass technology. The AM40-0023 is designed specifically for use in DCS-1800 and PCS telecommunication applications where less than 1 dB noise figure is required.

CR-5



Electrical Specifications:

Bias Conditions: +7V @ 20 mA Typical (each channel), T_A = +25°C, Z₀ = 50 Ohms

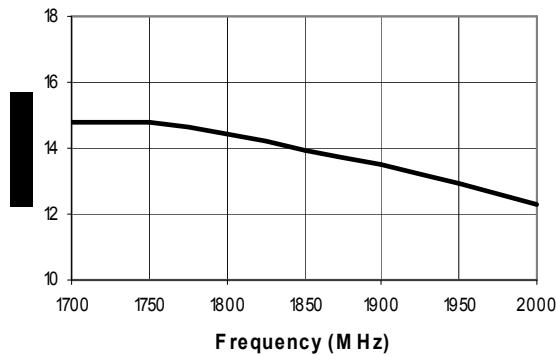
Parameter	Test Conditions	Frequency	Units	Min.	Typ.	Max.
Gain	P _{IN} = -20 dBm	1.710-1.910 GHz	dB	11	14	—
Gain Flatness	P _{IN} = -20 dBm	1.710-1.910 GHz	dB	—	± 1.0	± 1.5
Noise Figure	—	1.710-1.910 GHz	dB	—	0.7	0.9
VSWR Input	P _{IN} = -20 dBm	1.710-1.910 GHz	Ratio	—	2.0:1	3.0:1
VSWR Output	P _{IN} = -20 dBm	1.710-1.910 GHz	Ratio	—	2.0:1	3.0:1
1 dB Compression	Input Power	1.710-1.910 GHz	dBm	-13	-9	—
Reverse Isolation	—	1.710-1.910 GHz	dB	20	25	—
Input Third Order Intercept	—	1.710-1.910 GHz	dBm	0	3	—

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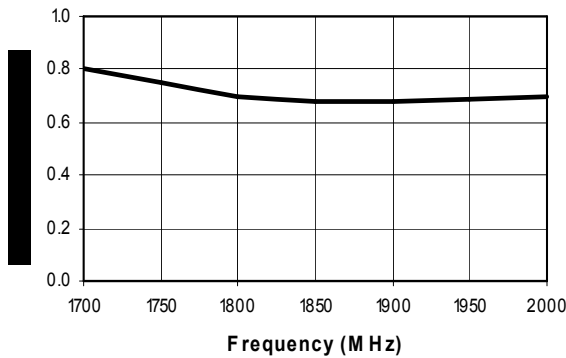
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Typical Performance Curves

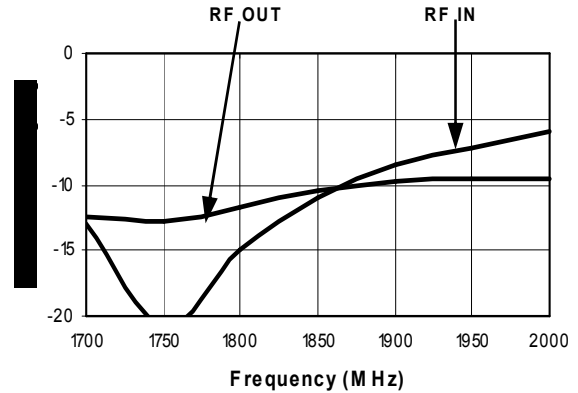
Gain vs. Frequency



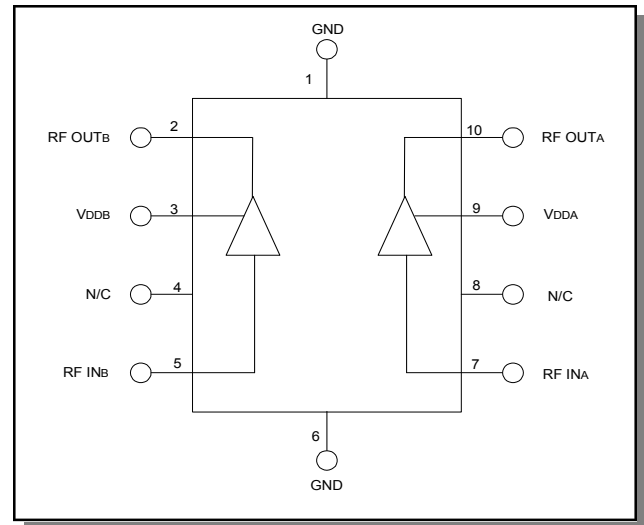
Noise Figure vs. Frequency



Input & Output Return Loss



Functional Schematic (Top View)



Absolute Maximum Ratings ¹

Parameter	Absolute Maximum
Max. Input Power ²	+15 dBm
Operating Voltage ²	+10.0 V
Operating Temperature	-55°C to +125°C
Storage Temperature	-65°C to +150°C

1. Operation of this device above any one of these parameters may cause permanent damage.
2. Ambient Temperature (T_A) = +25°C

Ordering Information

Part Number	Package
AM40-0023 PIN	CR-5